

Automotive-grade high voltage ignition coil driver NPN power Darlington transistor

Datasheet - production data

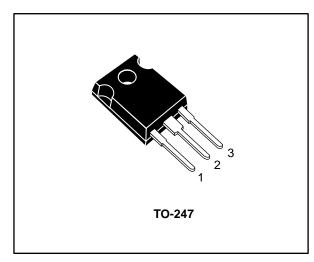
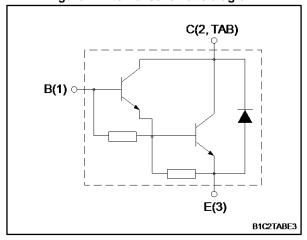


Figure 1: Internal schematic diagram



Features



- AEC-Q101 qualified
- Very rugged Bipolar technology
- High operating junction temperature

Applications

• High ruggedness electronic ignitions

Description

This is a high voltage power Darlington transistor developed using multi-epitaxial planar technology. It has been properly designed for automotive environment as electronic ignition power actuators.

Table 1: Device summary

Order code	Marking	Package	Packing
BU931P	BU931P	TO-247	Tube

Contents BU931P

Contents

1	Electric	cal ratings	3
2	Electric	cal characteristics	4
	2.1	Electrical characteristics (curves)	5
3	Test cir	rcuits	7
4	Packag	ge information	8
	4.1	TO-247 package information	8
5	Revisio	on history	10

BU931P Electrical ratings

1 Electrical ratings

Table 2: Absolute maximum ratings

Symbol	Parameter	Value	Unit
Vces	Collector-emitter voltage (V _{BE} = 0)	500	V
V _{CEO}	Collector-emitter voltage (I _B = 0)	400	V
V _{EBO}	Emitter-base voltage (I _C = 0)	5	V
Ic Collector current		15	Α
I _{CM} Collector peak current		30	Α
I _B Base current		1	Α
I _{BM} Base peak current		5	Α
P _{TOT} Total dissipation at Tc = 25 °C		135	W
T _{stg}	T _{stg} Storage temperature range		°C
Tj	T _j Operating junction temperature range		°C

Table 3: Thermal data

Symbol	Parameter	Value	Unit
RthJC	Thermal resistance junction-case	1.1	°C/W
R _{thJA}	Thermal resistance junction-ambient	50	°C/W

Electrical characteristics BU931P

2 Electrical characteristics

(T_C = 25 °C unless otherwise specified)

Table 4: Electrical characteristics

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
	Collector cut-off current	V _{BE} = 0 V, V _{CE} = 500 V		-	100	μA
ICES		$V_{BE} = 0 \text{ V}, V_{CE} = 500 \text{ V},$ $T_{C} = 125 \text{ °C}$ (1)		1	0.5	mA
	Collector cut-off current	I _B = 0 A, V _{CE} = 450 V		ı	100	μΑ
ICEO		$I_B = 0 \text{ A}, V_{CE} = 450 \text{ V},$ $T_C = 125 ^{\circ}\text{C}$ (1)		-	0.5	mA
I _{EBO}	Emitter cut-off current	I _C = 0 A, V _{EB} = 5 V		-	20	mA
V _{CEO(sus)} ⁽²⁾	Collector-emitter sustaining voltage	I _B = 0 A, I _C = 100 mA	400	-		V
	Collector-emitter saturation voltage	I _C = 7 A, I _B = 70 mA		ı	1.6	V
V _{CE(sat)} (2)		I _C = 8 A, I _B = 100 mA		ı	1.8	V
		I _C = 10 A, I _B = 250 mA		ı	1.8	V
	Base-emitter saturation voltage	$I_C = 7 \text{ A}, I_B = 70 \text{ mA}$		-	2.2	V
V _{BE(sat)} ⁽²⁾		I _C = 8 A, I _B = 100 mA		-	2.4	V
		I _C = 10 A, I _B = 250 mA		-	2.5	V
h _{FE} ⁽²⁾	DC current gain	Ic = 5 A, VcE = 10 V	300	-		
VF	Diode forward voltage	I _F = 10 A		-	2.5	V
	Functional test	V _{CC} = 24 V, L = 7 mH, V _{clamp} = 400 V (see Figure 10: "Functional test circuit")	8	-		Α

Notes:

Table 5: Inductive load switching times

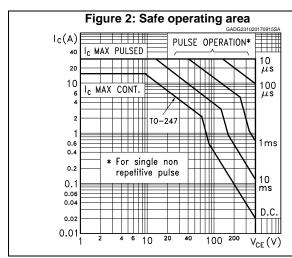
Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
ts	Storage time	V _{BE} =0, V _{CC} = 12 V,		15	-	μs
t _f	Fall time	$V_{\text{clamp}} = 300 \text{ V}, L = 7 \text{ mH},$ $R_{\text{BE}} = 47 \Omega, I_{\text{C}} = 7 \text{ A}, I_{\text{B}} = 70 \text{ mA}$ (see Figure 12: "Switching time test circuit")	-	0.5	-	μs

⁽¹⁾Defined by design, not subject to production test.

 $^{^{(2)}\}text{Pulse}$ test: pulse duration ≤ 300 µs, duty cycle ≤ 2 %.

BU931P Electrical characteristics

2.1 Electrical characteristics (curves)



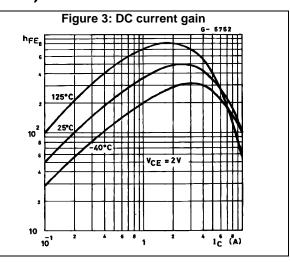


Figure 4: Switching time inductive load

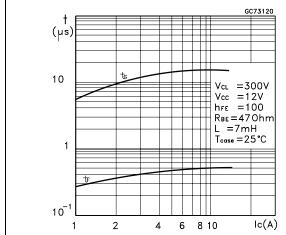
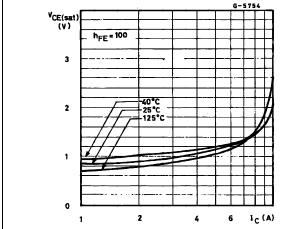


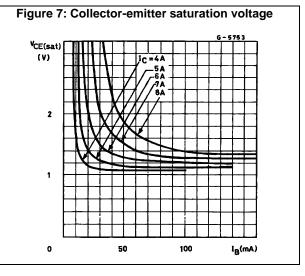
Figure 5: Collector-emitter saturation voltage @
hFE = 50

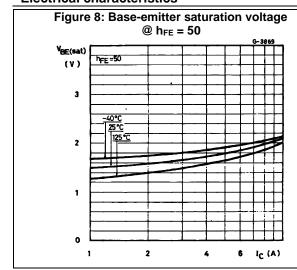
VCE(sat)
(V)
hFE=50
-40°C
-25°C
-125°C

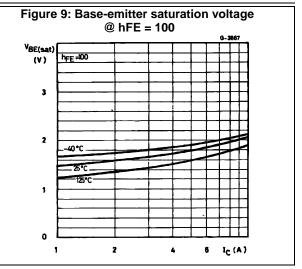
1
2
4 6 1_C (A)

Figure 6: Collector-emitter saturation voltage @ h_{FE} = 100



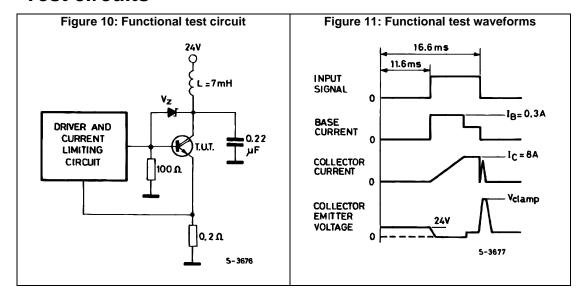


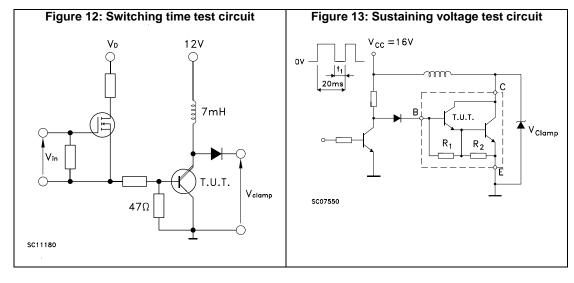




BU931P Test circuits

3 Test circuits





4 Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK® specifications, grade definitions and product status are available at: **www.st.com**. ECOPACK® is an ST trademark.

4.1 TO-247 package information

Figure 14: TO-247 package outline HEAT-SINK PLANE øΡ S øR Ľ2 *b1 b2* BACK VIEW 0075325_8

Dim	mm				
Dim.	Min.	Тур.	Max.		
А	4.85		5.15		
A1	2.20		2.60		
b	1.0		1.40		
b1	2.0		2.40		
b2	3.0		3.40		
С	0.40		0.80		
D	19.85		20.15		
Е	15.45		15.75		
е	5.30	5.45	5.60		
L	14.20		14.80		
L1	3.70		4.30		
L2		18.50			
ØP	3.55		3.65		
ØR	4.50		5.50		
S	5.30	5.50	5.70		

Revision history BU931P

5 Revision history

Table 7: Document revision history

Date	Revision	Changes
23-Oct-2017	1	Initial release. Part number previously included in datasheet DocID1004.

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